



# PS2801C-1, PS2801C-4

## **Data Sheet**

R08DS0072EJ0400 Rev.4.00 Jan 9, 2013

#### HIGH ISOLATION VOLTAGE SSOP PHOTOCOUPLER

#### **DESCRIPTION**

These products are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon phototransistor in a plastic SSOP for high density applications to realize an excellent cost performance.

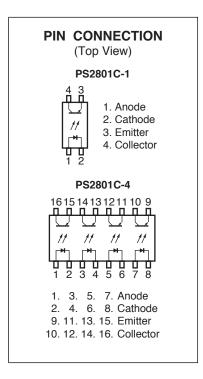
This package has shield effect to cut off ambient light.

#### **FEATURES**

- High isolation voltage (BV = 2 500 Vr.m.s.)
- Small and thin package (4, 16-pin SSOP, Pin pitch 1.27 mm)
- High collector to emitter voltage ( $V_{CEO}$ : 80 V)
- Ordering number of tape product: PS2801C-1-F3, PS2801C-4-F3
  - · Pb-Free product
- <R> Safety standards
  - UL approved: File No. E72422
  - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
  - BSI approved (BS EN 60065, BS EN 60950) (PS2801C-1 only)
  - DIN EN 60747-5-5 (VDE 0884-5) approved (Option)

#### **APPLICATIONS**

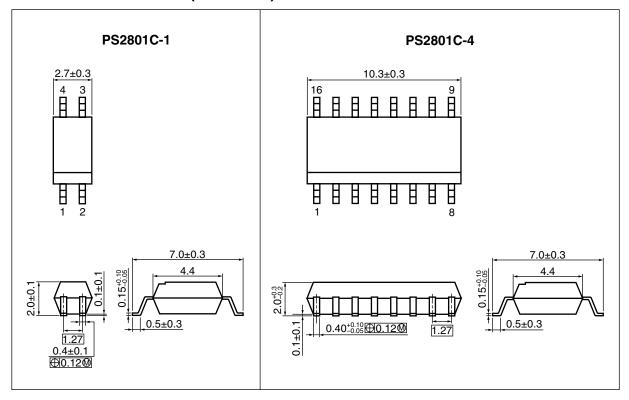
- Programmable logic controllers
- Measuring instruments
- Power supply
- Hybrid IC



The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

# PACKAGE DIMENSIONS (UNIT: mm)

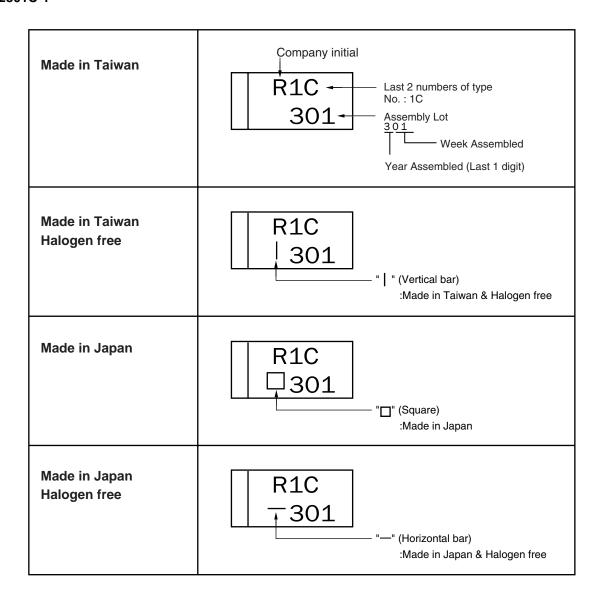


## <R> PHOTOCOUPLER CONSTRUCTION

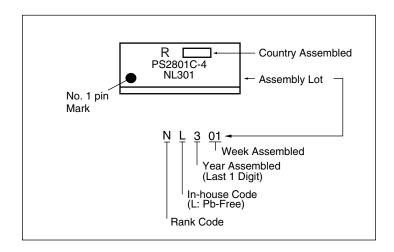
Parameter	Unit (MIN.)
Air Distance	4.5 mm
Outer Creepage Distance	4.5 mm
Inner Creepage Distance	2.5 mm
Isolation Distance	0.1 mm

### <R> MARKING EXAMPLE

#### PS2801C-1



### PS2801C-4





### <R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification etc.	Packing Style	Safety Standard Approval	Application Part Number*1
PS2801C-1-F3	PS2801C-1-F3-A	Pb-Free	Embossed Tape 3 500 pcs/reel	Standard products	PS2801C-1
PS2801C-4-F3	PS2801C-4-F3-A		Embossed Tape 2 500 pcs/reel	(UL, CSA, BSI approved)	PS2801C-4
PS2801C-1-V-F3	PS2801C-1-V-F3-A		Embossed Tape 3 500 pcs/reel	DIN EN 60747-5-5	PS2801C-1
PS2801C-4-V-F3	PS2801C-4-V-F3-A		Embossed Tape 2 500 pcs/reel	(VDE0884-5) Approved (Option)	PS2801C-4
PS2801C-1-F3	PS2801C-1Y-F3-A	Special version (Pb-Free and Halogen Free)	Embossed Tape 3 500 pcs/reel	Standard products (UL, CSA, BSI approved)	PS2801C-1
PS2801C-1-V-F3	PS2801C-1Y-V-F3-A		Embossed Tape 3 500 pcs/reel	DIN EN 60747-5-5 (VDE0884-5) Approved (Option)	

Note: \*1. For the application of the Safety Standard, following part number should be used.

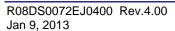
## ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C, unless otherwise specified)

Parameter		Symbol	Rat	Unit	
			PS2801C-1	PS2801C-4	
Diode	Forward Current (DC)	I <sub>F</sub>	3	80	mA/ch
	Reverse Voltage	V <sub>R</sub>		6	V
	Power Dissipation Derating	⊿P <sub>D</sub> /°C	0.6	0.8	mW/°C
	Power Dissipation	P <sub>D</sub>	60	80	mW/ch
	Peak Forward Current*1	I <sub>FP</sub>	0	0.5	
Transistor	Collector to Emitter Voltage	V <sub>CEO</sub>	80		V
	Emitter to Collector Voltage	V <sub>ECO</sub>	5		V
	Collector Current	Ic	30		mA/ch
	Power Dissipation Derating	⊿P <sub>0</sub> /°C	1.2		mW/°C
	Power Dissipation	Pc	1:	20	mW/ch
Isolation Voltage *2		BV	2 500		Vr.m.s.
Operating A	Operating Ambient Temperature		-55 to +100		°C
Storage Temperature		$T_{stg}$	-55 to +150		°C

Notes: \*1. PW = 100  $\mu$ s, Duty Cycle = 1%

\*2. AC voltage for 1 minute at  $T_A = 25$ °C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together (PS2801C-1).

Pins 1-8 shorted together, 9-16 shorted together (PS2801C-4).





# ELECTRICAL CHARACTERISTICS ( $T_A = 25$ °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	$V_{F}$	I <sub>F</sub> = 5 mA		1.2	1.4	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 5 V			5	μА
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		10		pF
Transistor	Collector to Emitter Dark Current	I <sub>CEO</sub>	V <sub>CE</sub> = 80 V, I <sub>F</sub> = 0 mA			100	nA
Coupled	Current Transfer Ratio (I <sub>C</sub> /I <sub>F</sub> ) *1	CTR	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	50		400	%
	Collector Saturation Voltage	V <sub>CE (sat)</sub>	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 2 mA		0.13	0.3	V
	Isolation Resistance	R <sub>I-O</sub>	$V_{I-O} = 1.0 \text{ kV}_{DC}$	10 <sup>11</sup>			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1.0 MHz		0.4		pF
	Rise Time *2	t <sub>r</sub>	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$		5		μs
	Fall Time *2	t <sub>f</sub>			7		
	Turn-on Time *2	t <sub>on</sub>			10		
	Turn-off Time *2	t <sub>off</sub>			7		

<R> <R>

Notes: \*1. CTR rank

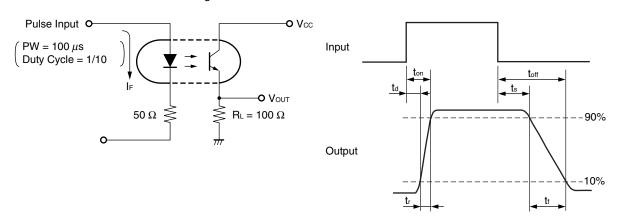
PS2801C-1

N: 50 to 400 (%)
P: 150 to 300 (%)
L: 100 to 300 (%)
M: 100 to 400 (%)

PS2801C-4

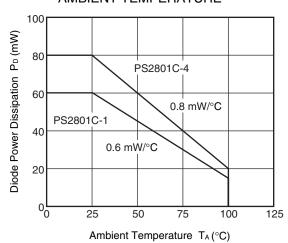
N: 50 to 400 (%) M: 100 to 400 (%)

\*2. Test circuit for switching time

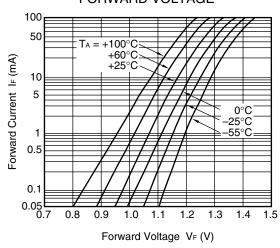


## <R> TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise specified)

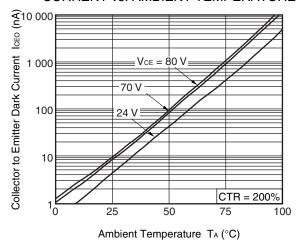
#### DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



#### FORWARD CURRENT vs. FORWARD VOLTAGE

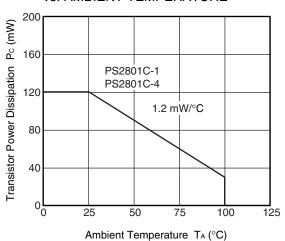


#### COLLECTOR TO EMITTER DARK **CURRENT vs. AMBIENT TEMPERATURE**

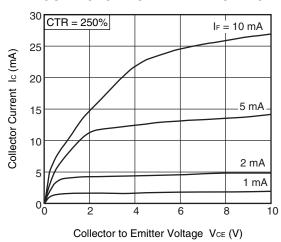


Remark The graphs indicate nominal characteristics.

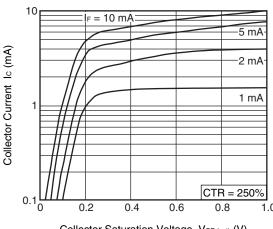
#### TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



#### COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

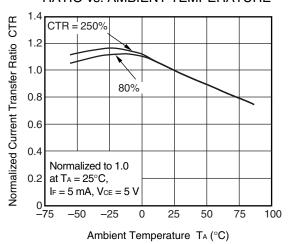


#### COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**

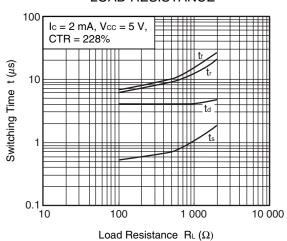


Collector Saturation Voltage VcE (sat) (V)

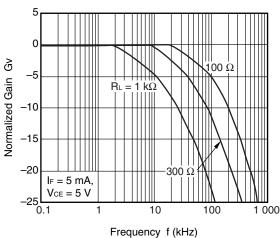
# NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



# SWITCHING TIME vs. LOAD RESISTANCE

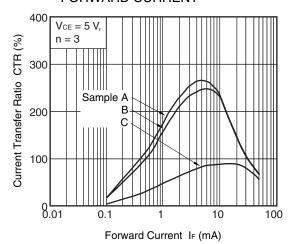


#### FREQUENCY RESPONSE

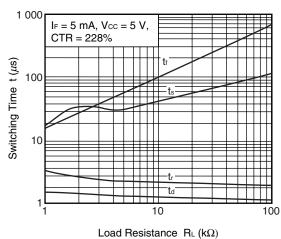


Remark The graphs indicate nominal characteristics.

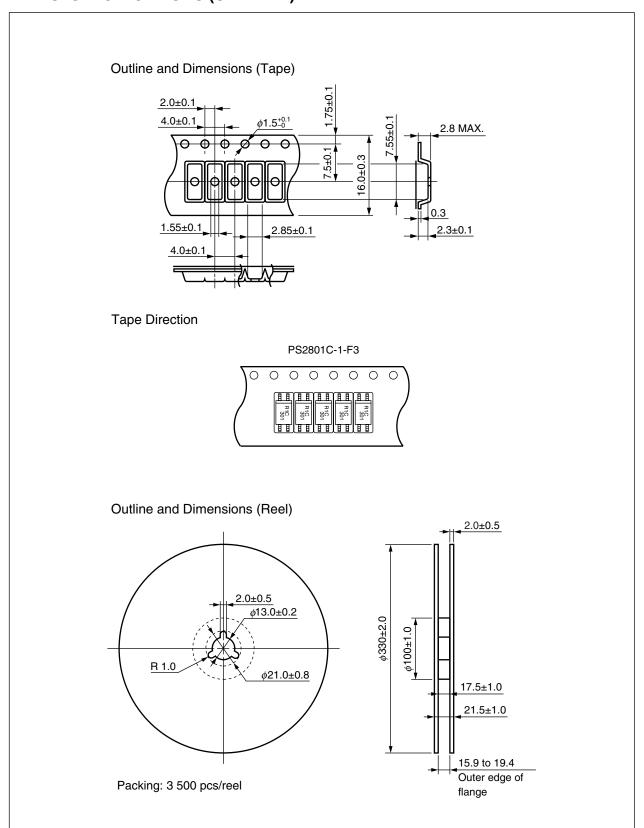
# CURRENT TRANSFER RATIO vs. FORWARD CURRENT

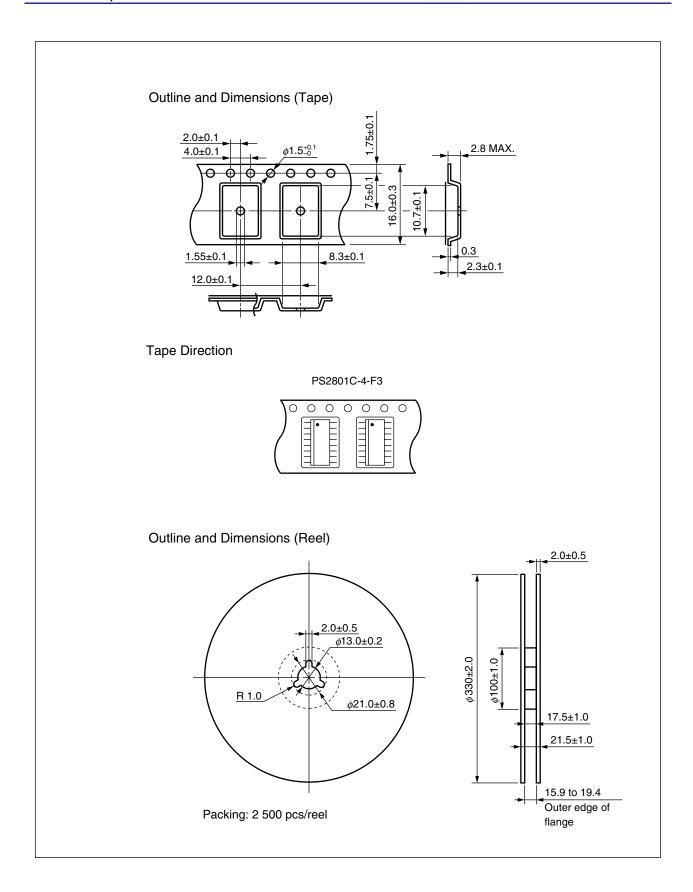


# SWITCHING TIME vs. LOAD RESISTANCE



## <R> TAPING SPECIFICATIONS (UNIT: mm)





#### <R> NOTES ON HANDLING

- 1. Recommended soldering conditions
  - (1) Infrared reflow soldering
    - Peak reflow temperature
    - Time of peak reflow temperature
    - Time of temperature higher than 220°C
    - Time to preheat temperature from 120 to 180°C
    - · Number of reflows
    - Flux

260°C or below (package surface temperature)

10 seconds or less

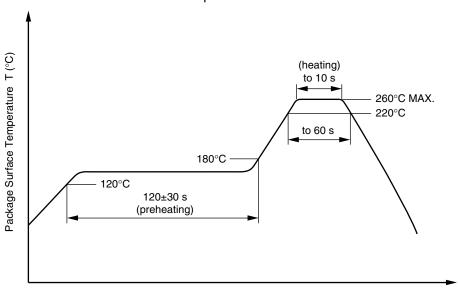
60 seconds or less

120±30 s

Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### Recommended Temperature Profile of Infrared Reflow



Time (s)

#### (2) Wave soldering

Temperature

• Time

• Preheating conditions

· Number of times

• Flux

260°C or below (molten solder temperature)

10 seconds or less

120°C or below (package surface temperature)

One (Allowed to be dipped in solder including plastic

mold portion.)

Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

#### (3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature)

• Time (each pins)

• Flux

350°C or below

3 seconds or less

Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

#### (4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

### PS2801C-1, PS2801C-4



2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collectoremitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler
 Check the setting values before use, since the forward current conditions at CTR measurement differ according to
 product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below  $I_F = 1 \text{ mA}$ .

Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

### **USAGE CAUTIONS**

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.



## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

	Parameter	Symbol	Spec.	Unit
	Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
	Dielectric strength			
	maximum operating isolation voltage	$U_IORM$	705	$V_{peak}$
<r></r>	Test voltage (partial discharge test, procedure a for type test and	$U_pr$	1 128	$V_{peak}$
	random test)			
<r></r>	$U_{pr} = 1.6 \times U_{IORM}, P_d < 5 pC$			
	Test voltage (partial discharge test, procedure b for all devices)	$U_pr$	1 322	$V_{peak}$
	$U_{pr} = 1.875 \times U_{IORM}, P_d < 5 pC$			
	Highest permissible overvoltage	$U_TR$	6 000	$V_{peak}$
.п.	Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
<r></r>	Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303	CTI	175	
	Part 11))			
	Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
	Storage temperature range	$T_{stg}$	−55 to +150	°C
	Operating temperature range	$T_A$	−55 to +100	°C
	Isolation resistance, minimum value			
	$V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$	Ris MIN.	10 <sup>12</sup>	Ω
	V <sub>IO</sub> = 500 V dc at T <sub>A</sub> MAX. at least 100°C	Ris MIN.	10 <sup>11</sup>	Ω
	Safety maximum ratings (maximum permissible in case of fault, see			
	thermal derating curve)			
	Package temperature	Tsi	150	°C
	Current (input current $I_F$ , $Psi = 0$ )	lsi	300	mA
	Power (output or total power dissipation)	Psi	500	mW
	Isolation resistance			
	$V_{IO} = 500 \text{ V dc at } T_A = Tsi$	Ris MIN.	10 <sup>9</sup>	Ω

# PS2801C-1, PS2801C-4 Data Sheet

			Description		
Rev. Date		Page	Summary		
1.00	May 30, 2006	_	This data sheet was released as PN10610EJ01V0DS		
4.00	Jan 9, 2013	Throughout	Renesas format is applied to this data sheet.		
		p.1	The ordering number and safety standards are revised.		
		p.2	PHOTOCOUPLER CONSTRUCTION is added as each distance of this device.		
		p.3	The explanation in MARKING EXAMPLE is revised.		
		p.4	ORDERING INFORMATION is modified with the revision of the safety standards.		
		p.5	Turn-on Time (t <sub>on</sub> ) and Turn-off Time (t <sub>off</sub> ) are added to the table in ELECTRICAL CHARACTERISTICS.		
		p.7	The graph of LONG TERM CTR DEGRADATION is deleted from those in TYPICAL CHARACTERISTICS.		
		p.8	PS2801C-1-F4 is deleted form Tape Direction image in TAPING SPECIFICATIONS.		
		p.9	PS2801C-4-F4 is deleted form Tape Direction image in TAPING SPECIFICATIONS.		
		p.10	The note about temperature condition of the recommended soldering conditions is deleted.		
		p.12	The values in SPECIFICATION OF VDE MARKS LICENSE DOCUMENT are changed as follows.		
			Test voltage is changed from the factor, 1.5, and the value, 1058, to 1.6 and 1128, respectively.		
			Clearance distance is moved to PHOTOCOUPLER CONSTRUCTION with changing 5.0 (min.) to 4.5 (min.).		

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